## **OPB916** Series

## Features:

- Low power consumption
- Data rates to 250 kBaud
- Choice of two logic states and two electrical outputs
- 24" (610 mm) minimum 26 AWG UL listed wires
- Slot width 0.20" (5.08 mm)
- Slot Depth 0.635" (16.13 mm)

# Electronics

#### **Description:**

The **OPB916** series of Photologic<sup>®</sup> photo integrated circuit switches provide optimum flexibility. Each switch consists of an infrared Light Emitting Diode (LED) and a Photologic<sup>®</sup> photo integrated circuit, mounted in an opaque housing with clear windows for dust protection. The deep slot allows for a longer reach of the optical path from the 0.650" (16.5 mm) mounting plane. Internal apertures are 0.010" x .060" (.25 mm x 1.52 mm) for the Photologic's "S" side and 0.05" x 0.06" (1.27 mm x 1.52 mm) for the LED "E" side.

Devices in this series exhibit stable performance over supply voltages ranging from 4.5 V to 16.0 V, and may be specified as buffered with an internal 10 k $\Omega$  pull-up resistor or open collector output. Devices are TTL/LSTTL compatible and can drive up to 10 TTL loads.

LED

Peak

Wavelength

880 nm

**Ordering Information** 

Sensor

**Photologic®** 

10 K Pull-Up

Inv-10 K Pull-Up

**Open-Collector** 

Custom electrical, wire or cabling are available. Contact your local representative or OPTEK for more information.

### **Applications:**

- Mechanical switch replacement
- Speed indication (tachometer)
- Mechanical limit indication
- Edge sensing

Color	Description			
Red	Anode			
Black	Cathode			
White	V <sub>cc</sub>			
Blue	Output			
Green	Ground			

#### OPB916BZ 10 K Pull-Up

Part

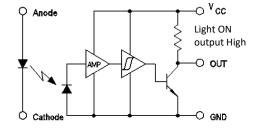
Number

**OPB916BZ** 

**OPB916IZ** 

**Obsolete** 

OPB916BOCZ



#### **OPB916BOCZ Open-Collector**

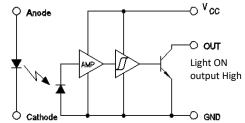
Slot

Width /

Depth

0.200" /

0.635"



Aperture

Emitter /

Sensor

0.05" /

0.01"

Lead

Length /

Wire

24" / 26

AWG Wire

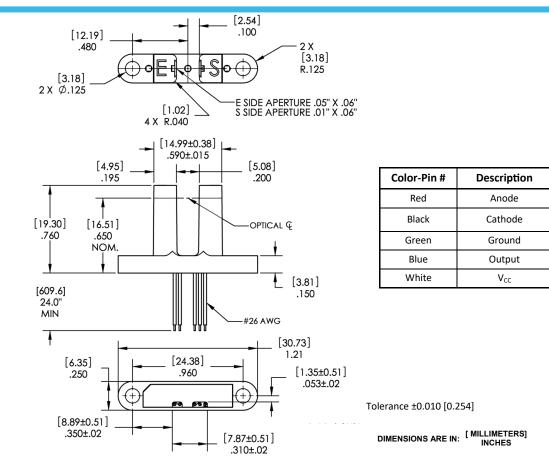


General Note

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## **OPB916 Series**





#### **Absolute Maximum Ratings** (T<sub>A</sub> = 25° C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +80° C
Input Infrared LED	
Diode Reverse DC Voltage	2 V
Input Diode Power Dissipation <sup>(2)</sup>	75 mW
Forward DC Current	50 mA
Output Photologic®	
Supply Voltage, V <sub>cc</sub> (not to exceed 3 seconds)	18 V
Voltage at Output Lead (Open Collector Output)	30 V
Output Photologic <sup>®</sup> Power Dissipation <sup>(3)</sup>	90 mW

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.67 mW/° C above 25°.
- (3) Derate linearly 2.67 mW/° C above 25°.
- (4) Normal application would be with light source blocked, simulated by  $I_F = 0$  mA.
- (5) All parameters tested using pulse technique.

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## **OPB916 Series**



## Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	МАХ	UNITS	TEST CONDITIONS
Input Diode	2	•				
$V_{\rm F}$	Forward Voltage	-	1.3	1.8	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	Reverse Current	-	-	100	μΑ	V <sub>R</sub> = 2 V, T <sub>A</sub> = 25° C
Output Pho	tologic <sup>®</sup> Sensor					
$V_{cc}$	Operating DC Supply Voltage	4.5	-	16	V	-
I <sub>CCL</sub>	Low Level Supply Current: Buffered with 10 k pull-up <sup>(1)</sup> Buffered Open-Collector Output <sup>(1)</sup>	-	-	7	mA	$V_{CC} = 16 V$ , $I_F = 0 mA$ , No Output Load
I <sub>ссн</sub>	High Level Supply Current: Buffered with 10 k pull-up Buffered Open-Collector Output	-	-	6	mA	$V_{CC}$ = 16 V, I <sub>F</sub> = 10 mA, No Output Load
V <sub>OL</sub>	Low Level Output Voltage: Buffered with 10 k pull-up Buffered Open-Collector Output	-	-	0.4	V	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA, I <sub>F</sub> = 0 mA
V <sub>OH</sub>	High Level Output Voltage: Buffered with 10 k pull-up	V <sub>cc</sub> - 2.0	-	-	V	$V_{CC}$ = 4.5 V to 16 V, $I_F$ = 10 mA, $I_{OH}$ = 100 $\mu A$
I <sub>OH</sub>	High Level Output Current: Buffered with 10 k pull-up Buffered Open-Collector Output	-	1.0	10	μΑ	V <sub>CC</sub> = 4.5 V, I <sub>F</sub> = 10 mA, V <sub>OH</sub> = 30 V
I <sub>F(+)</sub>	LED Positive-Going Threshold Current Buffered with 10 k pull-up	-	5	10	mA	V <sub>cc</sub> = 5 V, No Output Load
	Buffered Open-Collector Output	-	5	10	mA	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 16 mA
I <sub>F(+)</sub> /I <sub>F(-)</sub>	Hysteresis	-	1.5	-	-	V <sub>cc</sub> = 5 V
t <sub>r,</sub> t <sub>f</sub>	Rise Time, Fall Time	-	50	-	ns	$V_{cc} = 5 V$ , $I_F = 0 \text{ or } 10 \text{ mA}$ , R <sub>L</sub> = 300 Ω to 5 V, C <sub>L</sub> = 50 pF
t <sub>PLH,</sub> t <sub>PHL</sub>	Propagation Delay	-	3	-	μs	

Notes:

(1) Normal application would be with light source blocked, simulated by  $I_F = 0$  mA.

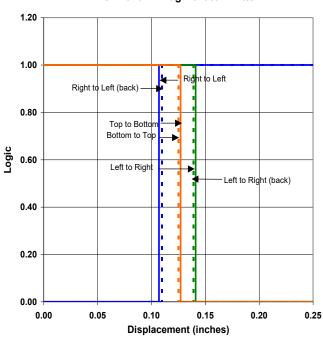
(2) All parameters tested using pulse technique.

General Note

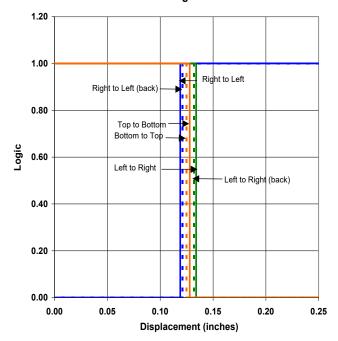
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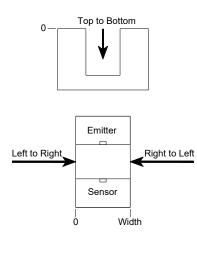




**OPB916B - Flag Next to Emitter** 



**OPB916B - Flag Next to Sensor** 



1.00 Right to Left Right to Left (back) 0.80 Top to Bottom Bottom to Top Logic 0.60 Left to Right Left to Right (back) 0.40

**OPB916B - Flag in Middle of Slot** 

General Note

0.20

0.00 0.00

0.05

1.20

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0.10

**Distance (inches)** 

0.15

0.20

0.25